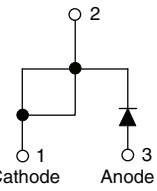
Ultrafast Soft Recovery Diode, 60 A FRED Pt®

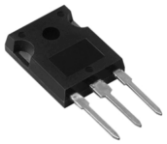
60EPU06PbF

Cathode to base

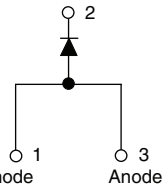


TO-247AC modified

60APU06PbF



Cathode to base



TO-247AC

FEATURES

- Ultrafast recovery
- 175 °C operating junction temperature
- Compliant to RoHS directive 2002/95/EC
- Designed and qualified for industrial level

Pb-free Available

RoHS* COMPLIANT

BENEFITS

- Reduced RFI and EMI
- Higher frequency operation
- Reduced snubbing
- Reduced parts count

DESCRIPTION/APPLICATIONS

These diodes are optimized to reduce losses and EMI/RFI in high frequency power conditioning systems.

The softness of the recovery eliminates the need for a snubber in most applications. These devices are ideally suited for HF welding, power converters and other applications where switching losses are not significant portion of the total losses.

PRODUCT SUMMARY	
t_{rr} (typical)	34 ns
$I_{F(AV)}$	60 A
V_R	600 V

ABSOLUTE MAXIMUM RATINGS				
PARAMETER	**SYMBOL**	**TEST CONDITIONS**	**MAX.**	**UNITS**
Cathode to anode voltage	V_R		600	V
Continuous forward current	$I_{F(AV)}$	T_C = 116 °C	60	A
Single pulse forward current	I_{FSM}	T_C = 25 °C	600	
Maximum repetitive forward current	I_{FRM}	Square wave, 20 kHz	120	
Operating junction and storage temperatures	T_J, T_{Stg}		- 55 to 175	°C

ELECTRICAL SPECIFICATIONS (T_J = 25 °C unless otherwise specified)						
PARAMETER	**SYMBOL**	**TEST CONDITIONS**	**MIN.**	**TYP.**	**MAX.**	**UNITS**
Breakdown voltage, blocking voltage	V_{BR}, V_R	I_R = 100 µA	600	-	-	V
Forward voltage	V_F	I_F = 60 A	-	1.35	1.68	
		I_F = 60 A, T_J = 125 °C	-	1.20	1.42	
		I_F = 60 A, T_J = 175 °C	-	1.11	1.30	
Reverse leakage current	I_R	V_R = V_R rated	-	-	50	µA
		T_J = 150 °C, V_R = V_R rated	-	-	500	
Junction capacitance	C_T	V_R = 600 V	-	39	-	pF

* Pb containing terminations are not RoHS compliant, exemptions may apply

DYNAMIC RECOVERY CHARACTERISTICS (T_J = 25 °C unless otherwise specified)							
PARAMETER	**SYMBOL**	**TEST CONDITIONS**		**MIN.**	**TYP.**	**MAX.**	**UNITS**
Reverse recovery time	t_{rr}	I_F = 1 A, dI_F/dt = 200 A/µs, V_R = 30 V		-	34	45	ns
		T_J = 25 °C	I_F = 60 A dI_F/dt = 200 A/µs V_R = 200 V	-	81	-	
		T_J = 125 °C		-	164	-	
Peak recovery current	I_{RRM}	T_J = 25 °C		-	7.4	-	A
		T_J = 125 °C		-	17.0	-	
Reverse recovery charge	Q_{rr}	T_J = 25 °C		-	300	-	nC
		T_J = 125 °C		-	1394	-	

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER	**SYMBOL**	**TEST CONDITIONS**	**MIN.**	**TYP.**	**MAX.**	**UNITS**
Thermal resistance, junction to case	R_{thJC}		-	-	0.63	K/W
Thermal resistance, case to heatsink	R_{thCS}	Mounting surface, flat, smooth and greased	-	0.2	-	
Weight			-	5.5	-	g
			-	0.2	-	oz.
Mounting torque			1.2 (10)	-	2.4 (20)	N · m (lbf · in)
Marking device		Case style TO-247AC modified	60EPU06			
		Case style TO-247AC	60APU06			

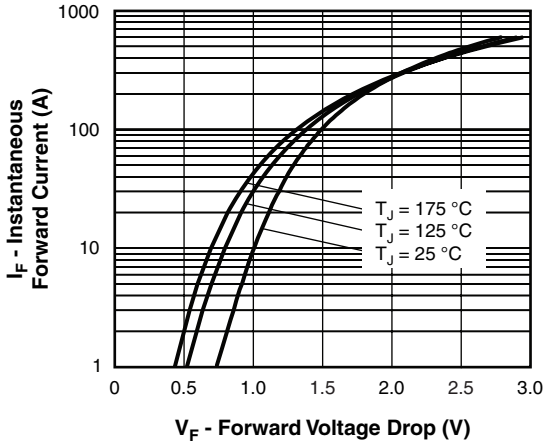


Fig. 1 - Typical Forward Voltage Drop Characteristics

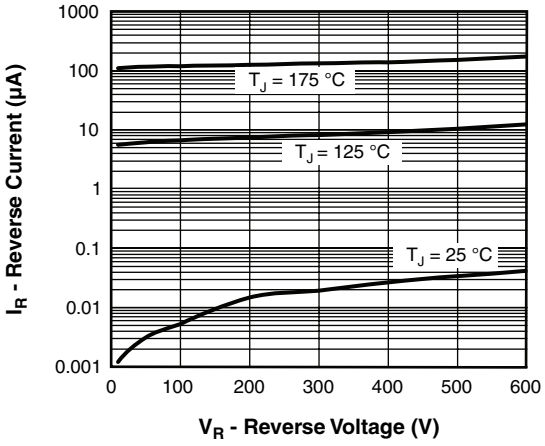


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

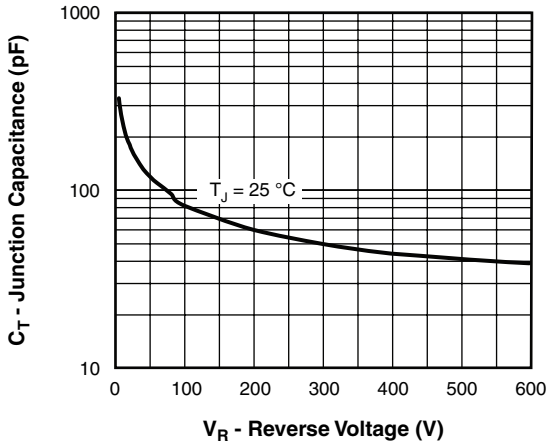


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

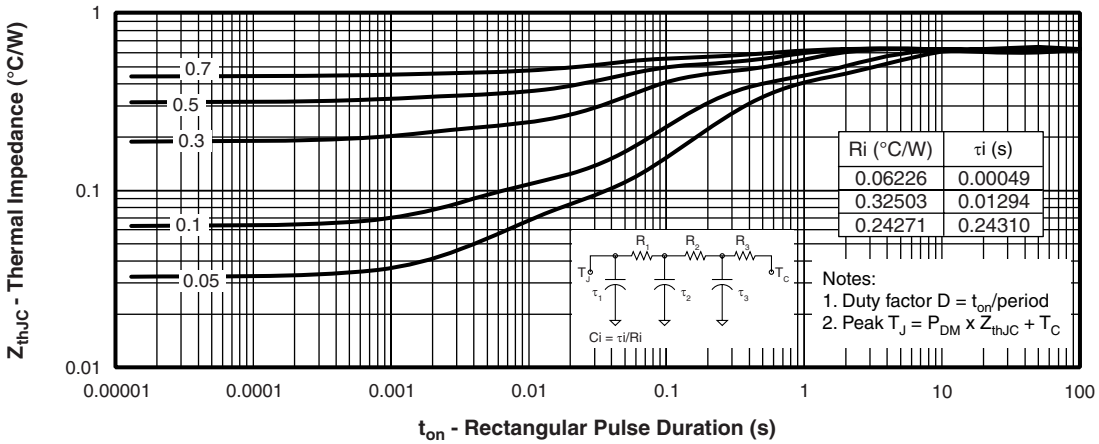


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

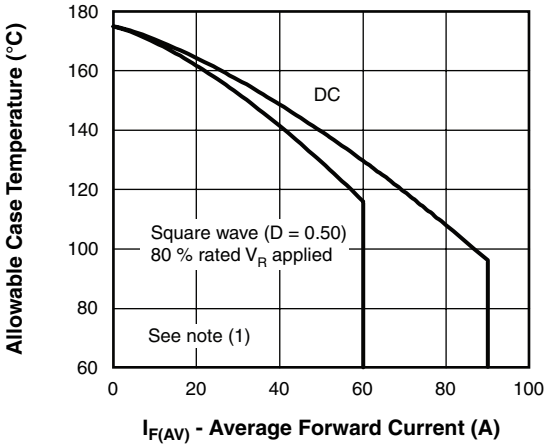


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current

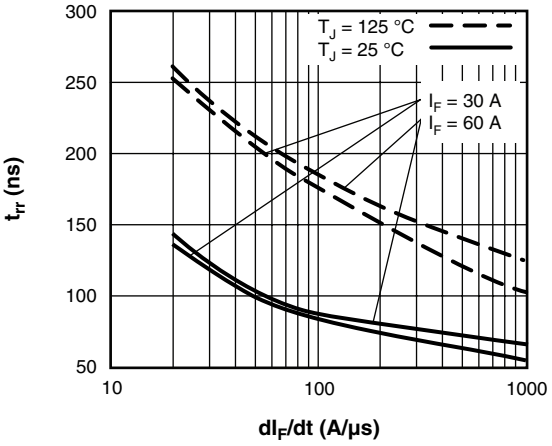


Fig. 7 - Typical Reverse Recovery Time vs. dI_F/dt

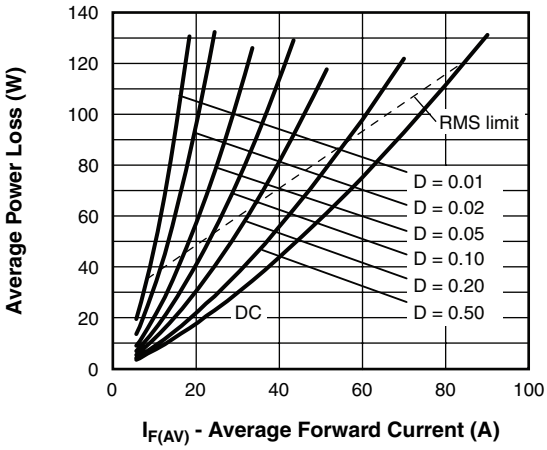


Fig. 6 - Forward Power Loss Characteristics

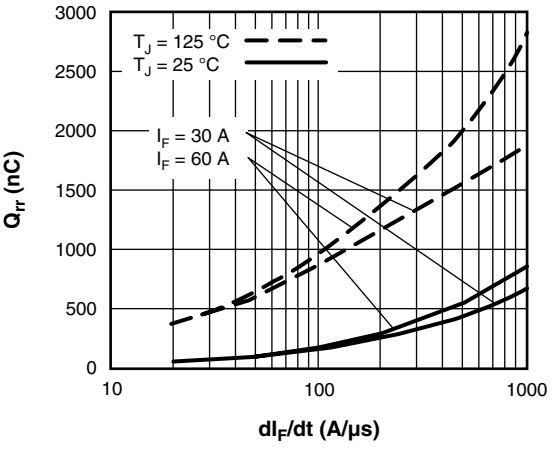


Fig. 8 - Typical Stored Charge vs. dI_F/dt

Note

(1) Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$;
Pd = Forward power loss = $I_{F(AV)} \times V_{FM}$ at ($I_{F(AV)}$/D) (see fig. 6);
Pd_{REV} = Inverse power loss = $V_{R1} \times I_R (1 - D)$; I_R at V_{R1} = 80 % rated V_R

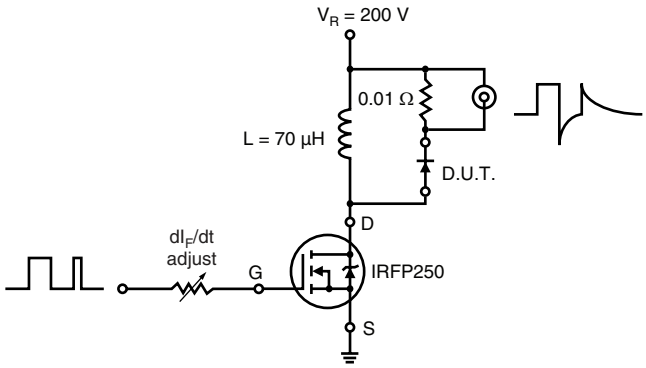
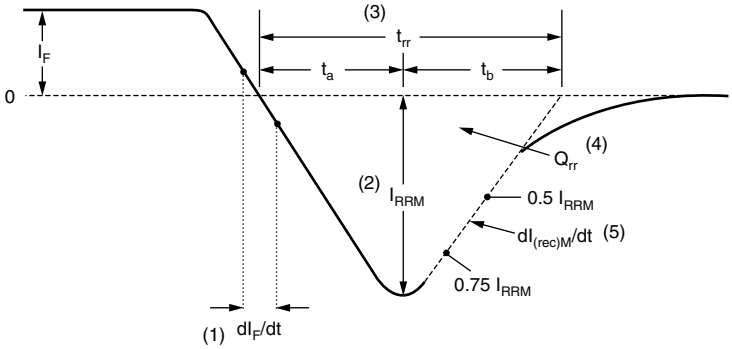


Fig. 9 - Reverse Recovery Parameter Test Circuit



(1) dI_F/dt - rate of change of current through zero crossing

(2) I_{RRM} - peak reverse recovery current

(3) t_{rr} - reverse recovery time measured from zero crossing point of negative going I_F to point where a line passing through 0.75 I_{RRM} and 0.50 I_{RRM} extrapolated to zero current.

(4) Q_{rr} - area under curve defined by t_{rr} and I_{RRM}

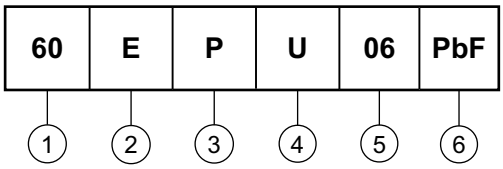
$$Q_{rr} = \frac{t_{rr} \times I_{RRM}}{2}$$

(5) $dI_{(rec)M}/dt$ - peak rate of change of current during t_b portion of t_{rr}

Fig. 10 - Reverse Recovery Waveform and Definitions

ORDERING INFORMATION TABLE

Device code



1 - Current rating (60 = 60 A)

2 - Circuit configuration:
- E = Single diode
- A = Single diode, 3 pins

3 - Package:
- P = TO-247AC (modified)

4 - Type of silicon:
- U = Ultrafast recovery

5 - Voltage rating (06 = 600 V)

6 - • None = Standard production
- • PbF = Lead (Pb)-free

LINKS TO RELATED DOCUMENTS		
Dimensions	TO-247AC modified	www.vishay.com/doc?95253
	TO-247AC	www.vishay.com/doc?95223
Part marking information	TO-247AC modified	www.vishay.com/doc?95255
	TO-247AC	www.vishay.com/doc?95226

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